



Dual P-Channel 12-V (D-S) MOSFET

PRODUCT SUMMARY				
V _{DS} (V)	$R_{DS(on)}(\Omega)$	I _D (A)		
- 12	0.042 at V _{GS} = - 4.5 V	- 6.5		
	0.058 at V _{GS} = - 2.5 V	- 5.5		
	0.082 at V _{GS} = - 1.8 V	- 1.2		

FEATURES

- Halogen-free Option Available
- TrenchFET[®] Power MOSFET: 1.8 V Rated

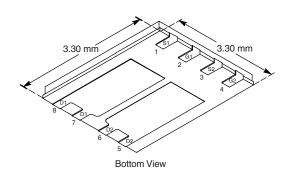


RoHS

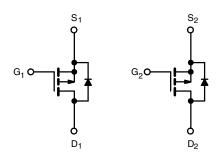
APPLICATIONS

- Load Switch
- PA Switch
- Battery Switch
- · Bi-Directional Switch

PowerPAK 1212-8



Ordering Information: Si7925DN-T1-E3 (Lead (Pb)-free) Si7925DN-T1-GE3 (Lead (Pb)-free and Halogen-free)



P-Channel MOSFET

P-Channel MOSFET

ABSOLUTE MAXIMUM RATINGS T_{A}	= 25 °C, unles	s otherwise n	oted		
Parameter		Symbol	10 s	Steady State	Unit
Drain-Source Voltage		V _{DS}	- 12		V
Gate-Source Voltage		V _{GS}	± 8		
Continuous Drain Current /T 150 °C\d	T _A = 25 °C	- I _D	- 6.5	- 4.8	^
Continuous Drain Current (T _J = 150 °C) ^a	T _A = 85 °C		- 4.7	- 3.4	
Pulsed Drain Current		I _{DM}	- 20		А
Continuous Source Current (Diode Conduction) ^a		I _S	- 2.1	- 1.1	
Mariana Barra Birain di ad	T _A = 25 °C	- P _D	2.5	1.3	W
Maximum Power Dissipation ^a	T _A = 85 °C		1.5	0.69	
Operating Junction and Storage Temperature Range		T _J , T _{stg}	- 55 to 150		°C
Soldering Recommendations (Peak Temperature) ^{b, c}			260		

THERMAL RESISTANCE RATINGS					
Parameter		Symbol	Typical	Maximum	Unit
Mariana la Anglianta	t ≤ 10 s	- R _{thJA}	40	50	°C/W
Maximum Junction-to-Ambient ^a	Steady State		75	94	
Maximum Junction-to-Case	Steady State	R_{thJC}	5.6	7	

Notes:

- a. Surface Mounted on 1" x 1" FR4 board.
- b. See Solder Profile (http://www.vishay.com/ppg?73257). The PowerPAK 1212-8 is a leadless package. The end of the lead terminal is exposed copper (not plated) as a result of the singulation process in manufacturing. A solder fillet at the exposed copper tip cannot be guaranteed and is not required to ensure adequate bottom side solder interconnection.
- c. Rework Conditions: manual soldering with a soldering iron is not recommended for leadless components.

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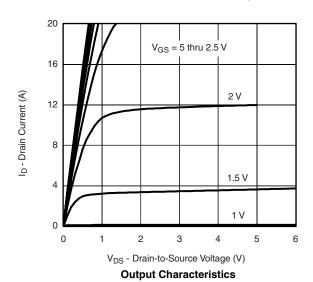
SPECIFICATIONS T _J = 25 °C, unless otherwise noted							
Parameter	Symbol	Test Conditions Min.		Тур.	Max.	Unit	
Static							
Gate Threshold Voltage	$V_{GS(th)}$	$V_{DS} = V_{GS}$, $I_D = -250 \mu A$	- 0.40		- 1.0	V	
Gate-Body Leakage	I _{GSS}	$V_{DS} = 0 V, V_{GS} = \pm 8 V$			± 100	nA	
Zero Gate Voltage Drain Current	I _{DSS}	V _{DS} = - 12 V, V _{GS} = 0 V			- 1		
		$V_{DS} = -12 \text{ V}, V_{GS} = 0 \text{ V}, T_{J} = 85 ^{\circ}\text{C}$			- 5	μΑ	
On-State Drain Current ^a	I _{D(on)}	$V_{DS} \le -5 \text{ V}, V_{GS} = -4.5 \text{ V}$	- 20			Α	
		V _{GS} = - 4.5 V, I _D = - 6.5 A		0.033	0.042		
Drain-Source On-State Resistance ^a	R _{DS(on)}	$V_{GS} = -2.5 \text{ V}, I_D = -5.5 \text{ A}$		0.046	0.058	Ω	
		V _{GS} = - 1.8 V, I _D = - 1.2 A		0.065	0.082	1	
Forward Transconductance ^a	9 _{fs}	V _{DS} = - 6 V, I _D = - 6.5 A		19		S	
Diode Forward Voltage ^a	V_{SD}	I _S = - 2.1 A, V _{GS} = 0 V		- 0.8	- 1.2	V	
Dynamic ^b							
Total Gate Charge	Q_g			11	12		
Gate-Source Charge	Q _{gs}	$V_{DS} = -6 \text{ V}, V_{GS} = -4.5 \text{ V}, I_{D} = -6.5 \text{ A}$		1.7		nC	
Gate-Drain Charge	Q_{gd}			2.8			
Gate Resistance	R_{g}			8.2		Ω	
Turn-On Delay Time	t _{d(on)}			20	30		
Rise Time	t _r	V_{DD} = - 6 V, R_L = 6 Ω		50	75		
Turn-Off Delay Time	t _{d(off)}	$I_D\cong$ - 1 A, $V_{GEN}=$ - 4.5 V, $R_G=6~\Omega$		70	105	ns	
Fall Time	t _f			50	75		
Source-Drain Reverse Recovery Time	t _{rr}	I _F = - 2.1 A, dI/dt = 100 A/μs		41	80		

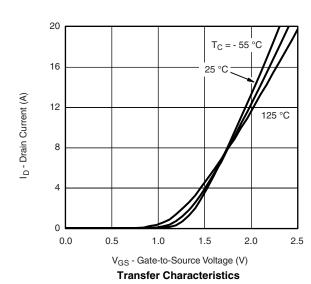
Notes:

- a. Pulse test; pulse width \leq 300 μ s, duty cycle \leq 2 %.
- b. Guaranteed by design, not subject to production testing.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted



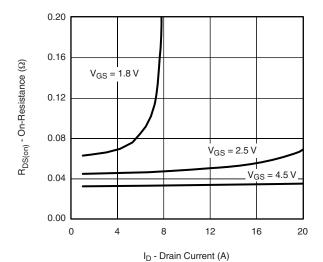




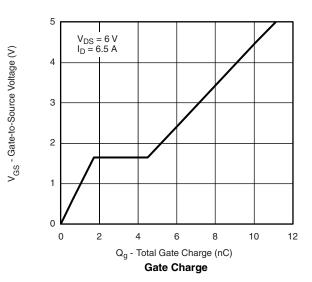


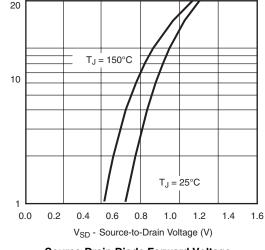


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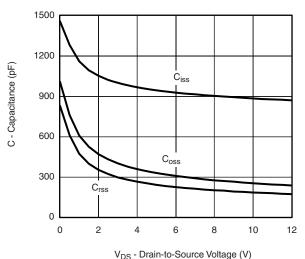


On-Resistance vs. Drain Current

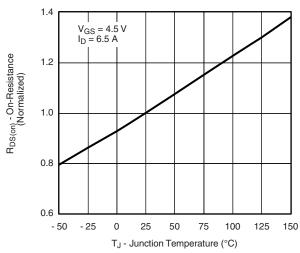




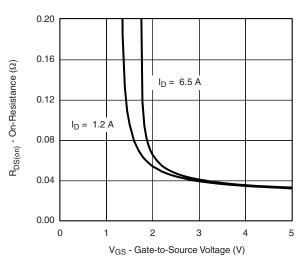
Source-Drain Diode Forward Voltage







On-Resistance vs. Junction Temperature



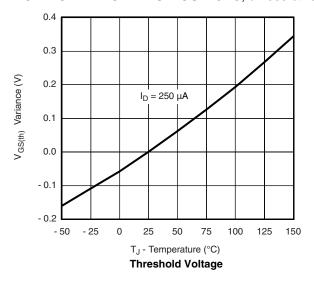
On-Resistance vs. Gate-to-Source Voltage

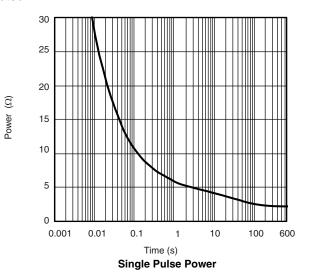
Is - Source Current (A)

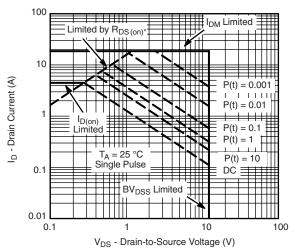
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TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted

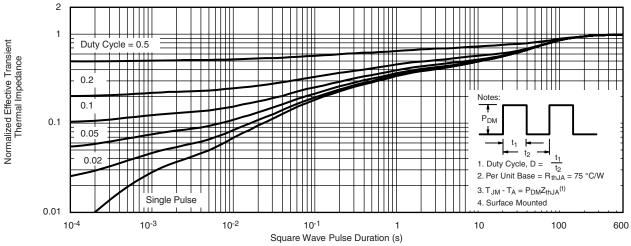






* V_{GS} > minimum V_{GS} at which $R_{DS(on)}$ is specified

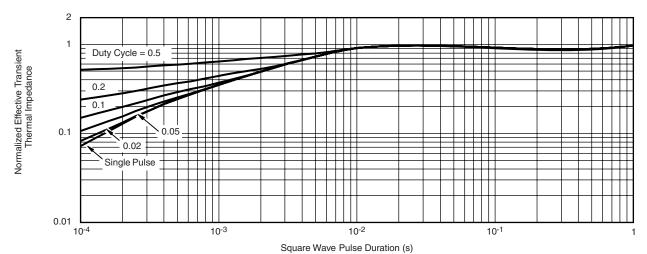
Safe Operating Area, Junction-to-Ambient



Normalized Thermal Transient Impedance, Junction-to-Ambient



TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted



Normalized Thermal Transient Impedance, Junction-to-Case

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